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### **Understanding [Embedded - FPGAs \(Field Programmable Gate Array\)](#)**

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

### **Applications of Embedded - FPGAs**

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

#### **Details**

Product Status	Obsolete
Number of LABs/CLBs	-
Number of Logic Elements/Cells	-
Total RAM Bits	36864
Number of I/O	84
Number of Gates	125000
Voltage - Supply	1.425V ~ 1.575V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 100°C (TJ)
Package / Case	132-WFQFN
Supplier Device Package	132-QFN (8x8)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/microsemi/a3p125-qng132i">https://www.e-xfl.com/product-detail/microsemi/a3p125-qng132i</a>

## Summary of I/O Timing Characteristics – Default I/O Software Settings

**Table 2-22 • Summary of AC Measuring Points**

Standard	Measuring Trip Point ( $V_{trip}$ )
3.3 V LVTTTL / 3.3 V LVCMOS	1.4 V
3.3 V LVCMOS Wide Range	1.4 V
2.5 V LVCMOS	1.2 V
1.8 V LVCMOS	0.90 V
1.5 V LVCMOS	0.75 V
3.3 V PCI	0.285 * VCCI (RR)
	0.615 * VCCI (FF)
3.3 V PCI-X	0.285 * VCCI (RR)
	0.615 * VCCI (FF)

**Table 2-23 • I/O AC Parameter Definitions**

Parameter	Parameter Definition
$t_{DP}$	Data to Pad delay through the Output Buffer
$t_{PY}$	Pad to Data delay through the Input Buffer
$t_{DOUT}$	Data to Output Buffer delay through the I/O interface
$t_{EOUT}$	Enable to Output Buffer Tristate Control delay through the I/O interface
$t_{DIN}$	Input Buffer to Data delay through the I/O interface
$t_{HZ}$	Enable to Pad delay through the Output Buffer—High to Z
$t_{ZH}$	Enable to Pad delay through the Output Buffer—Z to High
$t_{LZ}$	Enable to Pad delay through the Output Buffer—Low to Z
$t_{ZL}$	Enable to Pad delay through the Output Buffer—Z to Low
$t_{ZHS}$	Enable to Pad delay through the Output Buffer with delayed enable—Z to High
$t_{ZLS}$	Enable to Pad delay through the Output Buffer with delayed enable—Z to Low

**Table 2-24 • Summary of I/O Timing Characteristics—Software Default Settings**  
 –2 Speed Grade, Commercial-Case Conditions:  $T_J = 70^\circ\text{C}$ , Worst Case  $V_{CC} = 1.425\text{ V}$ ,  
 Worst-Case  $V_{CCI}$  (per standard)  
 Advanced I/O Banks

I/O Standard	Drive Strength	Equiv. Software Default Drive Strength Option <sup>1</sup>	Slew Rate	Capacitive Load (pF)	External Resistor ( $\Omega$ )	$t_{DOUT}$ (ns)	$t_{DP}$ (ns)	$t_{DIN}$ (ns)	$t_{PY}$ (ns)	$t_{EOUT}$ (ns)	$t_{ZL}$ (ns)	$t_{ZH}$ (ns)	$t_{LZ}$ (ns)	$t_{HZ}$ (ns)	$t_{ZLS}$ (ns)	$t_{ZHS}$ (ns)	Units
3.3 V LVTTTL / 3.3 V LVCMOS	12 mA	12 mA	High	35	–	0.45	2.64	0.03	0.76	0.32	2.69	2.11	2.40	2.68	4.36	3.78	ns
3.3 V LVCMOS Wide Range <sup>2</sup>	100 $\mu\text{A}$	12 mA	High	35	–	0.45	4.08	0.03	0.76	0.32	4.08	3.20	3.71	4.14	6.61	5.74	ns
2.5 V LVCMOS	12 mA	12 mA	High	35	–	0.45	2.66	0.03	0.98	0.32	2.71	2.56	2.47	2.57	4.38	4.23	ns
1.8 V LVCMOS	12 mA	12 mA	High	35	–	0.45	2.64	0.03	0.91	0.32	2.69	2.27	2.76	3.05	4.36	3.94	ns
1.5 V LVCMOS	12 mA	12 mA	High	35	–	0.45	3.05	0.03	1.07	0.32	3.10	2.67	2.95	3.14	4.77	4.34	ns
3.3 V PCI	Per PCI spec	–	High	10	25 <sup>4</sup>	0.45	2.00	0.03	0.65	0.32	2.04	1.46	2.40	2.68	3.71	3.13	ns
3.3 V PCI-X	Per PCI-X spec	–	High	10	25 <sup>4</sup>	0.45	2.00	0.03	0.62	0.32	2.04	1.46	2.40	2.68	3.71	3.13	ns
LVDS	24 mA	–	High	–	–	0.45	1.37	0.03	1.20	–	–	–	–	–	–	–	ns
LVPECL	24 mA	–	High	–	–	0.45	1.34	0.03	1.05	–	–	–	–	–	–	–	ns

**Notes:**

1. The minimum drive strength for any LVCMOS 3.3 V software configuration when run in wide range is  $\pm 100\ \mu\text{A}$ . Drive strength displayed in the software is supported for normal range only. For a detailed I/V curve, refer to the IBIS models.
2. All LVCMOS 3.3 V software macros support LVCMOS 3.3 V wide range as specified in the JESD-8B specification.
3. For specific junction temperature and voltage supply levels, refer to [Table 2-6 on page 2-6](#) for derating values.
4. Resistance is used to measure I/O propagation delays as defined in PCI specifications. See [Figure 2-11 on page 2-64](#) for connectivity. This resistor is not required during normal operation.

**Table 2-42 • 3.3 V LVTTTL / 3.3 V LVCMOS Low Slew**  
**Commercial-Case Conditions:  $T_J = 70^\circ\text{C}$ , Worst-Case  $V_{CC} = 1.425\text{ V}$ , Worst-Case  $V_{CCI} = 3.0\text{ V}$**   
**Applicable to Advanced I/O Banks**

Drive Strength	Speed Grade	$t_{DOUT}$	$t_{DP}$	$t_{DIN}$	$t_{PY}$	$t_{EOUT}$	$t_{ZL}$	$t_{ZH}$	$t_{LZ}$	$t_{HZ}$	$t_{ZLS}$	$t_{ZHS}$	Units
2 mA	Std.	0.66	10.26	0.04	1.02	0.43	10.45	8.90	2.64	2.46	12.68	11.13	ns
	-1	0.56	8.72	0.04	0.86	0.36	8.89	7.57	2.25	2.09	10.79	9.47	ns
	-2	0.49	7.66	0.03	0.76	0.32	7.80	6.64	1.98	1.83	9.47	8.31	ns
4 mA	Std.	0.66	10.26	0.04	1.02	0.43	10.45	8.90	2.64	2.46	12.68	11.13	ns
	-1	0.56	8.72	0.04	0.86	0.36	8.89	7.57	2.25	2.09	10.79	9.47	ns
	-2	0.49	7.66	0.03	0.76	0.32	7.80	6.64	1.98	1.83	9.47	8.31	ns
6 mA	Std.	0.66	7.27	0.04	1.02	0.43	7.41	6.28	2.98	3.04	9.65	8.52	ns
	-1	0.56	6.19	0.04	0.86	0.36	6.30	5.35	2.54	2.59	8.20	7.25	ns
	-2	0.49	5.43	0.03	0.76	0.32	5.53	4.69	2.23	2.27	7.20	6.36	ns
8 mA	Std.	0.66	7.27	0.04	1.02	0.43	7.41	6.28	2.98	3.04	9.65	8.52	ns
	-1	0.56	6.19	0.04	0.86	0.36	6.30	5.35	2.54	2.59	8.20	7.25	ns
	-2	0.49	5.43	0.03	0.76	0.32	5.53	4.69	2.23	2.27	7.20	6.36	ns
12 mA	Std.	0.66	5.58	0.04	1.02	0.43	5.68	4.87	3.21	3.42	7.92	7.11	ns
	-1	0.56	4.75	0.04	0.86	0.36	4.84	4.14	2.73	2.91	6.74	6.05	ns
	-2	0.49	4.17	0.03	0.76	0.32	4.24	3.64	2.39	2.55	5.91	5.31	ns
16 mA	Std.	0.66	5.21	0.04	1.02	0.43	5.30	4.56	3.26	3.51	7.54	6.80	ns
	-1	0.56	4.43	0.04	0.86	0.36	4.51	3.88	2.77	2.99	6.41	5.79	ns
	-2	0.49	3.89	0.03	0.76	0.32	3.96	3.41	2.43	2.62	5.63	5.08	ns
24 mA	Std.	0.66	4.85	0.04	1.02	0.43	4.94	4.54	3.32	3.88	7.18	6.78	ns
	-1	0.56	4.13	0.04	0.86	0.36	4.20	3.87	2.82	3.30	6.10	5.77	ns
	-2	0.49	3.62	0.03	0.76	0.32	3.69	3.39	2.48	2.90	5.36	5.06	ns

*Note:* For specific junction temperature and voltage supply levels, refer to [Table 2-6 on page 2-6](#) for derating values.

**Table 2-43 • 3.3 V LVTTTL / 3.3 V LVCMOS High Slew**  
**Commercial-Case Conditions:  $T_J = 70^\circ\text{C}$ , Worst-Case VCC = 1.425 V, Worst-Case VCCI = 3.0 V**  
**Applicable to Standard Plus I/O Banks**

Drive Strength	Speed Grade	$t_{DOUT}$	$t_{DP}$	$t_{DIN}$	$t_{PY}$	$t_{EOUT}$	$t_{ZL}$	$t_{ZH}$	$t_{LZ}$	$t_{HZ}$	$t_{ZLS}$	$t_{ZHS}$	Units
2 mA	Std.	0.66	7.20	0.04	1.00	0.43	7.34	6.29	2.27	2.34	9.57	8.52	ns
	-1	0.56	6.13	0.04	0.85	0.36	6.24	5.35	1.93	1.99	8.14	7.25	ns
	-2	0.49	5.38	0.03	0.75	0.32	5.48	4.69	1.70	1.75	7.15	6.36	ns
4 mA	Std.	0.66	7.20	0.04	1.00	0.43	7.34	6.29	2.27	2.34	9.57	8.52	ns
	-1	0.56	6.13	0.04	0.85	0.36	6.24	5.35	1.93	1.99	8.14	7.25	ns
	-2	0.49	5.38	0.03	0.75	0.32	5.48	4.69	1.70	1.75	7.15	6.36	ns
6 mA	Std.	0.66	4.50	0.04	1.00	0.43	4.58	3.82	2.58	2.88	6.82	6.05	ns
	-1	0.56	3.83	0.04	0.85	0.36	3.90	3.25	2.19	2.45	5.80	5.15	ns
	-2	0.49	3.36	0.03	0.75	0.32	3.42	2.85	1.92	2.15	5.09	4.52	ns
8 mA	Std.	0.66	4.50	0.04	1.00	0.43	4.58	3.82	2.58	2.88	6.82	6.05	ns
	-1	0.56	3.83	0.04	0.85	0.36	3.90	3.25	2.19	2.45	5.80	5.15	ns
	-2	0.49	3.36	0.03	0.75	0.32	3.42	2.85	1.92	2.15	5.09	4.52	ns
12 mA	Std.	0.66	3.16	0.04	1.00	0.43	3.22	2.58	2.79	3.22	5.45	4.82	ns
	-1	0.56	2.69	0.04	0.85	0.36	2.74	2.20	2.37	2.74	4.64	4.10	ns
	-2	0.49	2.36	0.03	0.75	0.32	2.40	1.93	2.08	2.41	4.07	3.60	ns
16 mA	Std.	0.66	3.16	0.04	1.00	0.43	3.22	2.58	2.79	3.22	5.45	4.82	ns
	-1	0.56	2.69	0.04	0.85	0.36	2.74	2.20	2.37	2.74	4.64	4.10	ns
	-2	0.49	2.36	0.03	0.75	0.32	2.40	1.93	2.08	2.41	4.07	3.60	ns

**Notes:**

1. Software default selection highlighted in gray.
2. For specific junction temperature and voltage supply levels, refer to [Table 2-6 on page 2-6](#) for derating values.

**Table 2-55 • 3.3 V LVTTTL / 3.3 V LVCMOS Low Slew**  
**Commercial-Case Conditions:  $T_J = 70^\circ\text{C}$ , Worst-Case VCC = 1.425 V, Worst-Case VCCI = 3.0 V**  
**Applicable to Standard I/O Banks**

Drive Strength	Equiv. Software Default Drive Strength Option <sup>1</sup>	Speed Grade	$t_{DOUT}$	$t_{DP}$	$t_{DIN}$	$t_{PY}$	$t_{EOUT}$	$t_{ZL}$	$t_{ZH}$	$t_{LZ}$	$t_{HZ}$	Units
100 $\mu\text{A}$	2 mA	Std.	0.60	14.64	0.04	1.52	0.43	14.64	12.97	3.21	3.15	ns
		-1	0.51	12.45	0.04	1.29	0.36	12.45	11.04	2.73	2.68	ns
		-2	0.45	10.93	0.03	1.13	0.32	10.93	9.69	2.39	2.35	ns
100 $\mu\text{A}$	4 mA	Std.	0.60	14.64	0.04	1.52	0.43	14.64	12.97	3.21	3.15	ns
		-1	0.51	12.45	0.04	1.29	0.36	12.45	11.04	2.73	2.68	ns
		-2	0.45	10.93	0.03	1.13	0.32	10.93	9.69	2.39	2.35	ns
100 $\mu\text{A}$	6 mA	Std.	0.60	10.16	0.04	1.52	0.43	10.16	9.08	3.71	3.98	ns
		-1	0.51	8.64	0.04	1.29	0.36	8.64	7.73	3.15	3.39	ns
		-2	0.45	7.58	0.03	1.13	0.32	7.58	6.78	2.77	2.97	ns
100 $\mu\text{A}$	8 mA	Std.	0.60	10.16	0.04	1.52	0.43	10.16	9.08	3.71	3.98	ns
		-1	0.51	8.64	0.04	1.29	0.36	8.64	7.73	3.15	3.39	ns
		-2	0.45	7.58	0.03	1.13	0.32	7.58	6.78	2.77	2.97	ns

**Notes:**

1. The minimum drive strength for any LVCMOS 3.3 V software configuration when run in wide range is  $\pm 100 \mu\text{A}$ . Drive strength displayed in the software is supported for normal range only. For a detailed I/V curve, refer to the IBIS models.
2. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

**Table 2-62 • 2.5 V LVC MOS High Slew**  
 Commercial-Case Conditions:  $T_J = 70^\circ\text{C}$ , Worst-Case  $V_{CC} = 1.425\text{ V}$ , Worst-Case  $V_{CCI} = 2.3\text{ V}$   
 Applicable to Standard Plus I/O Banks

Drive Strength	Speed Grade	$t_{DOUT}$	$t_{DP}$	$t_{DIN}$	$t_{PY}$	$t_{EOUT}$	$t_{ZL}$	$t_{ZH}$	$t_{LZ}$	$t_{HZ}$	$t_{ZLS}$	$t_{ZHS}$	Units
4 mA	Std.	0.66	8.28	0.04	1.30	0.43	7.41	8.28	2.25	2.07	9.64	10.51	ns
	-1	0.56	7.04	0.04	1.10	0.36	6.30	7.04	1.92	1.76	8.20	8.94	ns
	-2	0.49	6.18	0.03	0.97	0.32	5.53	6.18	1.68	1.55	7.20	7.85	ns
6 mA	Std.	0.66	4.85	0.04	1.30	0.43	4.65	4.85	2.59	2.71	6.88	7.09	ns
	-1	0.56	4.13	0.04	1.10	0.36	3.95	4.13	2.20	2.31	5.85	6.03	ns
	-2	0.49	3.62	0.03	0.97	0.32	3.47	3.62	1.93	2.02	5.14	5.29	ns
8 mA	Std.	0.66	4.85	0.04	1.30	0.43	4.65	4.85	2.59	2.71	6.88	7.09	ns
	-1	0.56	4.13	0.04	1.10	0.36	3.95	4.13	2.20	2.31	5.85	6.03	ns
	-2	0.49	3.62	0.03	0.97	0.32	3.47	3.62	1.93	2.02	5.14	5.29	ns
12 mA	Std.	0.66	3.21	0.04	1.30	0.43	3.27	3.14	2.82	3.11	5.50	5.38	ns
	-1	0.56	2.73	0.04	1.10	0.36	2.78	2.67	2.40	2.65	4.68	4.57	ns
	-2	0.49	2.39	0.03	0.97	0.32	2.44	2.35	2.11	2.32	4.11	4.02	ns

**Notes:**

1. Software default selection highlighted in gray.
2. For specific junction temperature and voltage supply levels, refer to [Table 2-6 on page 2-6](#) for derating values.

**Table 2-63 • 2.5 V LVC MOS Low Slew**  
 Commercial-Case Conditions:  $T_J = 70^\circ\text{C}$ , Worst-Case  $V_{CC} = 1.425\text{ V}$ , Worst-Case  $V_{CCI} = 2.3\text{ V}$   
 Applicable to Standard Plus I/O Banks

Drive Strength	Speed Grade	$t_{DOUT}$	$t_{DP}$	$t_{DIN}$	$t_{PY}$	$t_{EOUT}$	$t_{ZL}$	$t_{ZH}$	$t_{LZ}$	$t_{HZ}$	$t_{ZLS}$	$t_{ZHS}$	Units
4 mA	Std.	0.66	10.84	0.04	1.30	0.43	10.64	10.84	2.26	1.99	12.87	13.08	ns
	-1	0.56	9.22	0.04	1.10	0.36	9.05	9.22	1.92	1.69	10.95	11.12	ns
	-2	0.49	8.10	0.03	0.97	0.32	7.94	8.10	1.68	1.49	9.61	9.77	ns
6 mA	Std.	0.66	7.37	0.04	1.30	0.43	7.50	7.36	2.59	2.61	9.74	9.60	ns
	-1	0.56	6.27	0.04	1.10	0.36	6.38	6.26	2.20	2.22	8.29	8.16	ns
	-2	0.49	5.50	0.03	0.97	0.32	5.60	5.50	1.93	1.95	7.27	7.17	ns
8 mA	Std.	0.66	7.37	0.04	1.30	0.43	7.50	7.36	2.59	2.61	9.74	9.60	ns
	-1	0.56	6.27	0.04	1.10	0.36	6.38	6.26	2.20	2.22	8.29	8.16	ns
	-2	0.49	5.50	0.03	0.97	0.32	5.60	5.50	1.93	1.95	7.27	7.17	ns
12 mA	Std.	0.66	5.63	0.04	1.30	0.43	5.73	5.51	2.83	3.01	7.97	7.74	ns
	-1	0.56	4.79	0.04	1.10	0.36	4.88	4.68	2.41	2.56	6.78	6.59	ns
	-2	0.49	4.20	0.03	0.97	0.32	4.28	4.11	2.11	2.25	5.95	5.78	ns

**Note:** For specific junction temperature and voltage supply levels, refer to [Table 2-6 on page 2-6](#) for derating values.

**Table 2-64 • 2.5 V LVCMOS High Slew**

Commercial-Case Conditions:  $T_J = 70^\circ\text{C}$ , Worst-Case VCC = 1.425 V, Worst-Case VCCI = 3.0 V  
 Applicable to Standard I/O Banks

Drive Strength	Speed Grade	$t_{DOUT}$	$t_{DP}$	$t_{DIN}$	$t_{PY}$	$t_{EOUT}$	$t_{ZL}$	$t_{ZH}$	$t_{LZ}$	$t_{HZ}$	Units
2 mA	Std.	0.66	8.20	0.04	1.29	0.43	7.24	8.20	2.03	1.91	ns
	-1	0.56	6.98	0.04	1.10	0.36	6.16	6.98	1.73	1.62	ns
	-2	0.49	6.13	0.03	0.96	0.32	5.41	6.13	1.52	1.43	ns
4 mA	Std.	0.66	8.20	0.04	1.29	0.43	7.24	8.20	2.03	1.91	ns
	-1	0.56	6.98	0.04	1.10	0.36	6.16	6.98	1.73	1.62	ns
	-2	0.49	6.13	0.03	0.96	0.32	5.41	6.13	1.52	1.43	ns
6 mA	Std.	0.66	4.77	0.04	1.29	0.43	4.55	4.77	2.38	2.55	ns
	-1	0.56	4.05	0.04	1.10	0.36	3.87	4.05	2.03	2.17	ns
	-2	0.49	3.56	0.03	0.96	0.32	3.40	3.56	1.78	1.91	ns
8 mA	Std.	0.66	4.77	0.04	1.29	0.43	4.55	4.77	2.38	2.55	ns
	-1	0.56	4.05	0.04	1.10	0.36	3.87	4.05	2.03	2.17	ns
	-2	0.49	3.56	0.03	0.96	0.32	3.40	3.56	1.78	1.91	ns

**Notes:**

1. Software default selection highlighted in gray.
2. For specific junction temperature and voltage supply levels, refer to [Table 2-6 on page 2-6](#) for derating values.

**Table 2-65 • 2.5 V LVCMOS Low Slew**

Commercial-Case Conditions:  $T_J = 70^\circ\text{C}$ , Worst-Case VCC = 1.425 V, Worst-Case VCCI = 3.0 V  
 Applicable to Standard I/O Banks

Drive Strength	Speed Grade	$t_{DOUT}$	$t_{DP}$	$t_{DIN}$	$t_{PY}$	$t_{EOUT}$	$t_{ZL}$	$t_{ZH}$	$t_{LZ}$	$t_{HZ}$	Units
2 mA	Std.	0.66	11.00	0.04	1.29	0.43	10.37	11.00	2.03	1.83	ns
	-1	0.56	9.35	0.04	1.10	0.36	8.83	9.35	1.73	1.56	ns
	-2	0.49	8.21	0.03	0.96	0.32	7.75	8.21	1.52	1.37	ns
4 mA	Std.	0.66	11.00	0.04	1.29	0.43	10.37	11.00	2.03	1.83	ns
	-1	0.56	9.35	0.04	1.10	0.36	8.83	9.35	1.73	1.56	ns
	-2	0.49	8.21	0.03	0.96	0.32	7.75	8.21	1.52	1.37	ns
6 mA	Std.	0.66	7.50	0.04	1.29	0.43	7.36	7.50	2.39	2.46	ns
	-1	0.56	6.38	0.04	1.10	0.36	6.26	6.38	2.03	2.10	ns
	-2	0.49	5.60	0.03	0.96	0.32	5.49	5.60	1.78	1.84	ns
8 mA	Std.	0.66	7.50	0.04	1.29	0.43	7.36	7.50	2.39	2.46	ns
	-1	0.56	6.38	0.04	1.10	0.36	6.26	6.38	2.03	2.10	ns
	-2	0.49	5.60	0.03	0.96	0.32	5.49	5.60	1.78	1.84	ns

**Note:** For specific junction temperature and voltage supply levels, refer to [Table 2-6 on page 2-6](#) for derating values.

**Table 2-75 • 1.8 V LVCMOS Low Slew**

Commercial-Case Conditions:  $T_J = 70^\circ\text{C}$ , Worst-Case  $V_{CC} = 1.425\text{ V}$ , Worst-Case  $V_{CCI} = 3.0\text{ V}$   
 Applicable to Standard I/O Banks

Drive Strength	Speed Grade	$t_{DOUT}$	$t_{DP}$	$t_{DIN}$	$t_{PY}$	$t_{EOUT}$	$t_{ZL}$	$t_{ZH}$	$t_{LZ}$	$t_{HZ}$	Units
2 mA	Std.	0.66	15.01	0.04	1.20	0.43	13.15	15.01	1.99	1.99	ns
	-1	0.56	12.77	0.04	1.02	0.36	11.19	12.77	1.70	1.70	ns
	-2	0.49	11.21	0.03	0.90	0.32	9.82	11.21	1.49	1.49	ns
4 mA	Std.	0.66	10.10	0.04	1.20	0.43	9.55	10.10	2.41	2.37	ns
	-1	0.56	8.59	0.04	1.02	0.36	8.13	8.59	2.05	2.02	ns
	-2	0.49	7.54	0.03	0.90	0.32	7.13	7.54	1.80	1.77	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

### 1.5 V LVCMOS (JESD8-11)

Low-Voltage CMOS for 1.5 V is an extension of the LVCMOS standard (JESD8-5) used for general-purpose 1.5 V applications. It uses a 1.5 V input buffer and a push-pull output buffer.

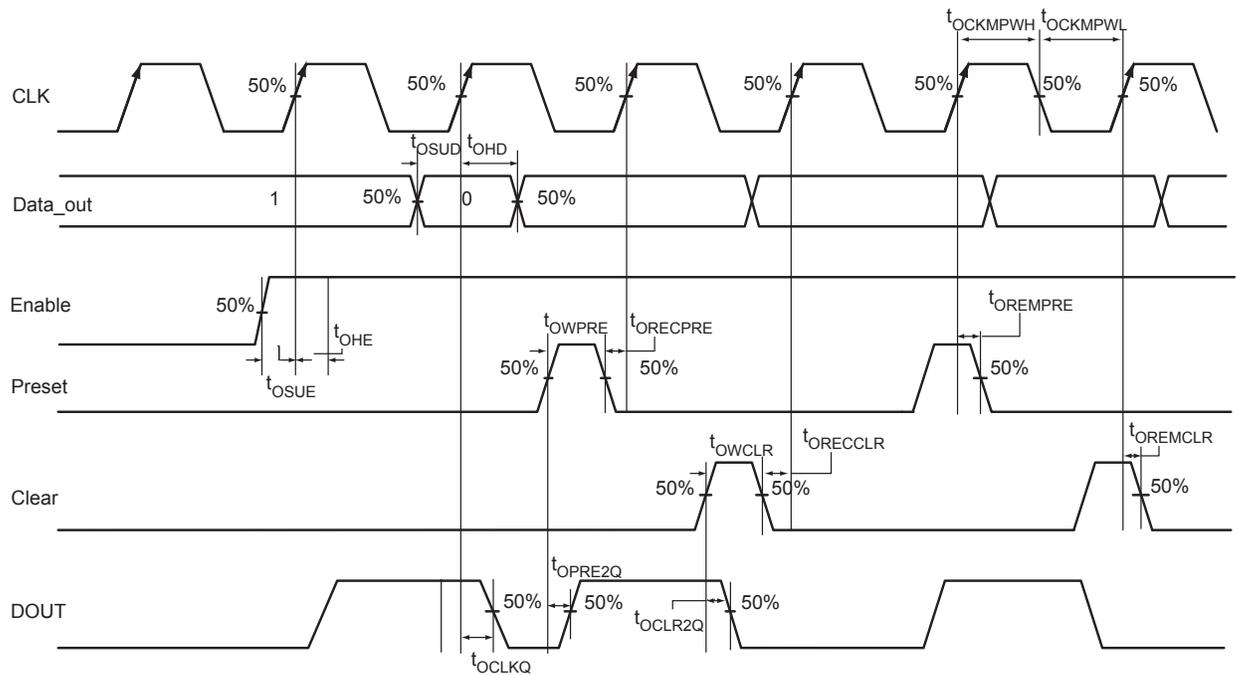
**Table 2-76 • Minimum and Maximum DC Input and Output Levels**  
 Applicable to Advanced I/O Banks

1.5 V LVCMOS	VIL		VIH		VOL	VOH	IOL	IOH	IOSL	IOSH	IIL <sup>1</sup>	IIH <sup>2</sup>
	Min. V	Max. V	Min. V	Max., V	Max. V	Min. V	mA	mA	Max. mA <sup>3</sup>	Max. mA <sup>3</sup>	$\mu\text{A}^4$	$\mu\text{A}^4$
2 mA	-0.3	0.35 * VCCI	0.65 * VCCI	1.575	0.25 * VCCI	0.75 * VCCI	2	2	16	13	10	10
4 mA	-0.3	0.35 * VCCI	0.65 * VCCI	1.575	0.25 * VCCI	0.75 * VCCI	4	4	33	25	10	10
6 mA	-0.3	0.35 * VCCI	0.65 * VCCI	1.575	0.25 * VCCI	0.75 * VCCI	6	6	39	32	10	10
8 mA	-0.3	0.35 * VCCI	0.65 * VCCI	1.575	0.25 * VCCI	0.75 * VCCI	8	8	55	66	10	10
12 mA	-0.3	0.35 * VCCI	0.65 * VCCI	1.575	0.25 * VCCI	0.75 * VCCI	12	12	55	66	10	10

Notes:

1. IIL is the input leakage current per I/O pin over recommended operation conditions where  $-0.3\text{ V} < V_{IN} < V_{IL}$ .
2. IIH is the input leakage current per I/O pin over recommended operating conditions  $V_{IH} < V_{IN} < V_{CCI}$ . Input current is larger when operating outside recommended ranges
3. Currents are measured at high temperature ( $100^\circ\text{C}$  junction temperature) and maximum voltage.
4. Currents are measured at  $85^\circ\text{C}$  junction temperature.
5. Software default selection highlighted in gray.

## Output Register



**Figure 2-18 • Output Register Timing Diagram**

### Timing Characteristics

**Table 2-99 • Output Data Register Propagation Delays**

Commercial-Case Conditions:  $T_J = 70^\circ\text{C}$ , Worst-Case  $V_{CC} = 1.425\text{ V}$

Parameter	Description	-2	-1	Std.	Units
$t_{OCLKQ}$	Clock-to-Q of the Output Data Register	0.59	0.67	0.79	ns
$t_{OSUD}$	Data Setup Time for the Output Data Register	0.31	0.36	0.42	ns
$t_{OHD}$	Data Hold Time for the Output Data Register	0.00	0.00	0.00	ns
$t_{OSUE}$	Enable Setup Time for the Output Data Register	0.44	0.50	0.59	ns
$t_{OHE}$	Enable Hold Time for the Output Data Register	0.00	0.00	0.00	ns
$t_{OCLR2Q}$	Asynchronous Clear-to-Q of the Output Data Register	0.80	0.91	1.07	ns
$t_{OPRE2Q}$	Asynchronous Preset-to-Q of the Output Data Register	0.80	0.91	1.07	ns
$t_{OREMCLR}$	Asynchronous Clear Removal Time for the Output Data Register	0.00	0.00	0.00	ns
$t_{ORECCLR}$	Asynchronous Clear Recovery Time for the Output Data Register	0.22	0.25	0.30	ns
$t_{OREMPRE}$	Asynchronous Preset Removal Time for the Output Data Register	0.00	0.00	0.00	ns
$t_{ORECPRE}$	Asynchronous Preset Recovery Time for the Output Data Register	0.22	0.25	0.30	ns
$t_{OWCLR}$	Asynchronous Clear Minimum Pulse Width for the Output Data Register	0.22	0.25	0.30	ns
$t_{OWPRE}$	Asynchronous Preset Minimum Pulse Width for the Output Data Register	0.22	0.25	0.30	ns
$t_{OCKMPWH}$	Clock Minimum Pulse Width High for the Output Data Register	0.36	0.41	0.48	ns
$t_{OCKMPWL}$	Clock Minimum Pulse Width Low for the Output Data Register	0.32	0.37	0.43	ns

*Note:* For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

## Timing Characteristics

**Table 2-116 • RAM4K9**

 Commercial-Case Conditions:  $T_j = 70^\circ\text{C}$ , Worst-Case  $V_{CC} = 1.425\text{ V}$ 

Parameter	Description	-2	-1	Std.	Units
$t_{AS}$	Address setup time	0.25	0.28	0.33	ns
$t_{AH}$	Address hold time	0.00	0.00	0.00	ns
$t_{ENS}$	REN, WEN setup time	0.14	0.16	0.19	ns
$t_{ENH}$	REN, WEN hold time	0.10	0.11	0.13	ns
$t_{BKS}$	BLK setup time	0.23	0.27	0.31	ns
$t_{BKH}$	BLK hold time	0.02	0.02	0.02	ns
$t_{DS}$	Input data (DIN) setup time	0.18	0.21	0.25	ns
$t_{DH}$	Input data (DIN) hold time	0.00	0.00	0.00	ns
$t_{CKQ1}$	Clock High to new data valid on DOUT (output retained, WMODE = 0)	2.36	2.68	3.15	ns
	Clock High to new data valid on DOUT (flow-through, WMODE = 1)	1.79	2.03	2.39	ns
$t_{CKQ2}$	Clock High to new data valid on DOUT (pipelined)	0.89	1.02	1.20	ns
$t_{C2CWWL}^1$	Address collision clk-to-clk delay for reliable write after write on same address—Applicable to Closing Edge	0.33	0.28	0.25	ns
$t_{C2CWWH}^1$	Address collision clk-to-clk delay for reliable write after write on same address—Applicable to Rising Edge	0.30	0.26	0.23	ns
$t_{C2CRWH}^1$	Address collision clk-to-clk delay for reliable read access after write on same address—Applicable to Opening Edge	0.45	0.38	0.34	ns
$t_{C2CWRH}^1$	Address collision clk-to-clk delay for reliable write access after read on same address—Applicable to Opening Edge	0.49	0.42	0.37	ns
$t_{RSTBQ}$	RESET Low to data out Low on DOUT (flow-through)	0.92	1.05	1.23	ns
	RESET Low to Data Out Low on DOUT (pipelined)	0.92	1.05	1.23	ns
$t_{REMRSTB}$	RESET removal	0.29	0.33	0.38	ns
$t_{RECRSTB}$	RESET recovery	1.50	1.71	2.01	ns
$t_{MPWRSTB}$	RESET minimum pulse width	0.21	0.24	0.29	ns
$t_{CYC}$	Clock cycle time	3.23	3.68	4.32	ns
$F_{MAX}$	Maximum frequency	310	272	231	MHz

### Notes:

1. For more information, refer to the application note [Simultaneous Read-Write Operations in Dual-Port SRAM for Flash-Based cSoCs and FPGAs](#).
2. For specific junction temperature and voltage supply levels, refer to [Table 2-6 on page 2-6](#) for derating values.

**Table 2-117 • RAM512X18****Commercial-Case Conditions:  $T_J = 70^\circ\text{C}$ , Worst-Case  $V_{CC} = 1.425\text{ V}$** 

Parameter	Description	-2	-1	Std.	Units
$t_{AS}$	Address setup time	0.25	0.28	0.33	ns
$t_{AH}$	Address hold time	0.00	0.00	0.00	ns
$t_{ENS}$	REN, WEN setup time	0.13	0.15	0.17	ns
$t_{ENH}$	REN, WEN hold time	0.10	0.11	0.13	ns
$t_{DS}$	Input data (WD) setup time	0.18	0.21	0.25	ns
$t_{DH}$	Input data (WD) hold time	0.00	0.00	0.00	ns
$t_{CKQ1}$	Clock High to new data valid on RD (output retained)	2.16	2.46	2.89	ns
$t_{CKQ2}$	Clock High to new data valid on RD (pipelined)	0.90	1.02	1.20	ns
$t_{C2CRWH}^1$	Address collision clk-to-clk delay for reliable read access after write on same address—Applicable to Opening Edge	0.50	0.43	0.38	ns
$t_{C2CWRH}^1$	Address collision clk-to-clk delay for reliable write access after read on same address—Applicable to Opening Edge	0.59	0.50	0.44	ns
$t_{RSTBQ}$	RESET Low to data out Low on RD (flow-through)	0.92	1.05	1.23	ns
	RESET Low to data out Low on RD (pipelined)	0.92	1.05	1.23	ns
$t_{REMRSTB}$	RESET removal	0.29	0.33	0.38	ns
$t_{RECRSTB}$	RESET recovery	1.50	1.71	2.01	ns
$t_{MPWRSTB}$	RESET minimum pulse width	0.21	0.24	0.29	ns
$t_{CYC}$	Clock cycle time	3.23	3.68	4.32	ns
$F_{MAX}$	Maximum frequency	310	272	231	MHz

**Notes:**

1. For more information, refer to the application note [Simultaneous Read-Write Operations in Dual-Port SRAM for Flash-Based cSoCs and FPGAs](#).
2. For specific junction temperature and voltage supply levels, refer to [Table 2-6 on page 2-6](#) for derating values.

<b>QN132</b>	
<b>Pin Number</b>	<b>A3P030 Function</b>
C17	IO51RSB1
C18	NC
C19	TCK
C20	NC
C21	VPUMP
C22	VJTAG
C23	NC
C24	NC
C25	NC
C26	GDB0/IO38RSB0
C27	NC
C28	VCCIB0
C29	IO32RSB0
C30	IO29RSB0
C31	IO28RSB0
C32	IO25RSB0
C33	NC
C34	NC
C35	VCCIB0
C36	IO17RSB0
C37	IO14RSB0
C38	IO11RSB0
C39	IO07RSB0
C40	IO04RSB0
D1	GND
D2	GND
D3	GND
D4	GND

<b>QN132</b>	
<b>Pin Number</b>	<b>A3P060 Function</b>
C17	IO57RSB1
C18	NC
C19	TCK
C20	VMV1
C21	VPUMP
C22	VJTAG
C23	VCCIB0
C24	NC
C25	NC
C26	GCA1/IO42RSB0
C27	GCC0/IO39RSB0
C28	VCCIB0
C29	IO29RSB0
C30	GNDQ
C31	GBA1/IO27RSB0
C32	GBB0/IO24RSB0
C33	VCC
C34	IO19RSB0
C35	IO16RSB0
C36	IO13RSB0
C37	GAC1/IO10RSB0
C38	NC
C39	GAA0/IO05RSB0
C40	VMV0
D1	GND
D2	GND
D3	GND
D4	GND

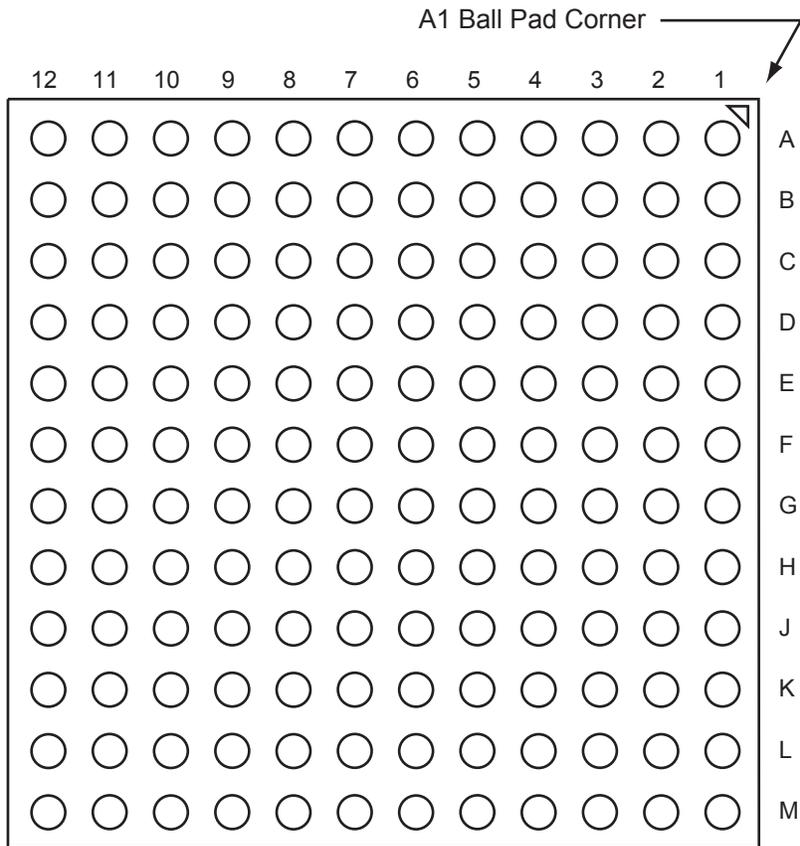
PQ208	
Pin Number	A3P600 Function
1	GND
2	GAA2/IO174PDB3
3	IO174NDB3
4	GAB2/IO173PDB3
5	IO173NDB3
6	GAC2/IO172PDB3
7	IO172NDB3
8	IO171PDB3
9	IO171NDB3
10	IO170PDB3
11	IO170NDB3
12	IO169PDB3
13	IO169NDB3
14	IO168PDB3
15	IO168NDB3
16	VCC
17	GND
18	VCCIB3
19	IO166PDB3
20	IO166NDB3
21	GFC1/IO164PDB3
22	GFC0/IO164NDB3
23	GFB1/IO163PDB3
24	GFB0/IO163NDB3
25	VCOMPLF
26	GFA0/IO162NPB3
27	VCCPLF
28	GFA1/IO162PPB3
29	GND
30	GFA2/IO161PDB3
31	IO161NDB3
32	GFB2/IO160PDB3
33	IO160NDB3
34	GFC2/IO159PDB3
35	IO159NDB3
36	VCC

PQ208	
Pin Number	A3P600 Function
37	IO152PDB3
38	IO152NDB3
39	IO150PSB3
40	VCCIB3
41	GND
42	IO147PDB3
43	IO147NDB3
44	GEC1/IO146PDB3
45	GEC0/IO146NDB3
46	GEB1/IO145PDB3
47	GEB0/IO145NDB3
48	GEA1/IO144PDB3
49	GEA0/IO144NDB3
50	VMV3
51	GNDQ
52	GND
53	VMV2
54	GEA2/IO143RSB2
55	GEB2/IO142RSB2
56	GEC2/IO141RSB2
57	IO140RSB2
58	IO139RSB2
59	IO138RSB2
60	IO137RSB2
61	IO136RSB2
62	VCCIB2
63	IO135RSB2
64	IO133RSB2
65	GND
66	IO131RSB2
67	IO129RSB2
68	IO127RSB2
69	IO125RSB2
70	IO123RSB2
71	VCC
72	VCCIB2

PQ208	
Pin Number	A3P600 Function
73	IO120RSB2
74	IO119RSB2
75	IO118RSB2
76	IO117RSB2
77	IO116RSB2
78	IO115RSB2
79	IO114RSB2
80	IO112RSB2
81	GND
82	IO111RSB2
83	IO110RSB2
84	IO109RSB2
85	IO108RSB2
86	IO107RSB2
87	IO106RSB2
88	VCC
89	VCCIB2
90	IO104RSB2
91	IO102RSB2
92	IO100RSB2
93	IO98RSB2
94	IO96RSB2
95	IO92RSB2
96	GDC2/IO91RSB2
97	GND
98	GDB2/IO90RSB2
99	GDA2/IO89RSB2
100	GNDQ
101	TCK
102	TDI
103	TMS
104	VMV2
105	GND
106	VPUMP
107	GNDQ
108	TDO

## FG144 – Bottom View

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### Note

For more information on package drawings, see [PD3068: Package Mechanical Drawings](#).

<b>FG144</b>	
<b>Pin Number</b>	<b>A3P250 Function</b>
K1	GEB0/IO99NDB3
K2	GEA1/IO98PDB3
K3	GEA0/IO98NDB3
K4	GEA2/IO97RSB2
K5	IO90RSB2
K6	IO84RSB2
K7	GND
K8	IO66RSB2
K9	GDC2/IO63RSB2
K10	GND
K11	GDA0/IO60VDB1
K12	GDB0/IO59VDB1
L1	GND
L2	VMV3
L3	GEB2/IO96RSB2
L4	IO91RSB2
L5	VCCIB2
L6	IO82RSB2
L7	IO80RSB2
L8	IO72RSB2
L9	TMS
L10	VJTAG
L11	VMV2
L12	TRST
M1	GNDQ
M2	GEC2/IO95RSB2
M3	IO92RSB2
M4	IO89RSB2
M5	IO87RSB2
M6	IO85RSB2
M7	IO78RSB2
M8	IO76RSB2
M9	TDI
M10	VCCIB2
M11	VPUMP
M12	GNDQ

FG484	
Pin Number	A3P600 Function
E21	NC
E22	NC
F1	NC
F2	NC
F3	NC
F4	IO173NDB3
F5	IO174NDB3
F6	VMV3
F7	IO07RSB0
F8	GAC0/IO04RSB0
F9	GAC1/IO05RSB0
F10	IO20RSB0
F11	IO24RSB0
F12	IO33RSB0
F13	IO39RSB0
F14	IO44RSB0
F15	GBC0/IO54RSB0
F16	IO51RSB0
F17	VMV0
F18	IO61NPB1
F19	IO63PDB1
F20	NC
F21	NC
F22	NC
G1	IO170NDB3
G2	IO170PDB3
G3	NC
G4	IO171NDB3
G5	IO171PDB3
G6	GAC2/IO172PDB3
G7	IO06RSB0
G8	GNDQ
G9	IO10RSB0
G10	IO19RSB0
G11	IO26RSB0
G12	IO30RSB0

FG484	
Pin Number	A3P600 Function
G13	IO40RSB0
G14	IO45RSB0
G15	GNDQ
G16	IO50RSB0
G17	GBB2/IO61PPB1
G18	IO53RSB0
G19	IO63NDB1
G20	NC
G21	NC
G22	NC
H1	NC
H2	NC
H3	VCC
H4	IO166PDB3
H5	IO167NPB3
H6	IO172NDB3
H7	IO169NDB3
H8	VMV0
H9	VCCIB0
H10	VCCIB0
H11	IO25RSB0
H12	IO31RSB0
H13	VCCIB0
H14	VCCIB0
H15	VMV1
H16	GBC2/IO62PDB1
H17	IO67PPB1
H18	IO64PPB1
H19	IO66PDB1
H20	VCC
H21	NC
H22	NC
J1	NC
J2	NC
J3	NC
J4	IO166NDB3

FG484	
Pin Number	A3P600 Function
J5	IO168NPB3
J6	IO167PPB3
J7	IO169PDB3
J8	VCCIB3
J9	GND
J10	VCC
J11	VCC
J12	VCC
J13	VCC
J14	GND
J15	VCCIB1
J16	IO62NDB1
J17	IO64NPB1
J18	IO65PPB1
J19	IO66NDB1
J20	NC
J21	IO68PDB1
J22	IO68NDB1
K1	IO157PDB3
K2	IO157NDB3
K3	NC
K4	IO165NDB3
K5	IO165PDB3
K6	IO168PPB3
K7	GFC1/IO164PPB3
K8	VCCIB3
K9	VCC
K10	GND
K11	GND
K12	GND
K13	GND
K14	VCC
K15	VCCIB1
K16	GCC1/IO69PPB1
K17	IO65NPB1
K18	IO75PDB1

FG484	
Pin Number	A3P1000 Function
R17	GDB1/IO112PPB1
R18	GDC1/IO111PDB1
R19	IO107NDB1
R20	VCC
R21	IO104NDB1
R22	IO105PDB1
T1	IO198PDB3
T2	IO198NDB3
T3	NC
T4	IO194PPB3
T5	IO192PPB3
T6	GEC1/IO190PPB3
T7	IO192NPB3
T8	GNDQ
T9	GEA2/IO187RSB2
T10	IO161RSB2
T11	IO155RSB2
T12	IO141RSB2
T13	IO129RSB2
T14	IO124RSB2
T15	GNDQ
T16	IO110PDB1
T17	VJTAG
T18	GDC0/IO111NDB1
T19	GDA1/IO113PDB1
T20	NC
T21	IO108PDB1
T22	IO105NDB1
U1	IO195PDB3
U2	IO195NDB3
U3	IO194NPB3
U4	GEB1/IO189PDB3
U5	GEB0/IO189NDB3
U6	VMV2
U7	IO179RSB2
U8	IO171RSB2

FG484	
Pin Number	A3P1000 Function
U9	IO165RSB2
U10	IO159RSB2
U11	IO151RSB2
U12	IO137RSB2
U13	IO134RSB2
U14	IO128RSB2
U15	VMV1
U16	TCK
U17	VPUMP
U18	TRST
U19	GDA0/IO113NDB1
U20	NC
U21	IO108NDB1
U22	IO109PDB1
V1	NC
V2	NC
V3	GND
V4	GEA1/IO188PDB3
V5	GEA0/IO188NDB3
V6	IO184RSB2
V7	GEC2/IO185RSB2
V8	IO168RSB2
V9	IO163RSB2
V10	IO157RSB2
V11	IO149RSB2
V12	IO143RSB2
V13	IO138RSB2
V14	IO131RSB2
V15	IO125RSB2
V16	GDB2/IO115RSB2
V17	TDI
V18	GNDQ
V19	TDO
V20	GND
V21	NC
V22	IO109NDB1

FG484	
Pin Number	A3P1000 Function
W1	NC
W2	IO191PDB3
W3	NC
W4	GND
W5	IO183RSB2
W6	GEB2/IO186RSB2
W7	IO172RSB2
W8	IO170RSB2
W9	IO164RSB2
W10	IO158RSB2
W11	IO153RSB2
W12	IO142RSB2
W13	IO135RSB2
W14	IO130RSB2
W15	GDC2/IO116RSB2
W16	IO120RSB2
W17	GDA2/IO114RSB2
W18	TMS
W19	GND
W20	NC
W21	NC
W22	NC
Y1	VCCIB3
Y2	IO191NDB3
Y3	NC
Y4	IO182RSB2
Y5	GND
Y6	IO177RSB2
Y7	IO174RSB2
Y8	VCC
Y9	VCC
Y10	IO154RSB2
Y11	IO148RSB2
Y12	IO140RSB2
Y13	NC
Y14	VCC

Revision	Changes	Page								
Advance v0.6 (continued)	The "Programming" section was updated to include information concerning serialization.	2-53								
	The "JTAG 1532" section was updated to include SAMPLE/PRELOAD information.	2-54								
	"DC and Switching Characteristics" chapter was updated with new information.	3-1								
	The A3P060 "100-Pin VQFP" pin table was updated.	4-13								
	The A3P125 "100-Pin VQFP" pin table was updated.	4-13								
	The A3P060 "144-Pin TQFP" pin table was updated.	4-16								
	The A3P125 "144-Pin TQFP" pin table was updated.	4-18								
	The A3P125 "208-Pin PQFP" pin table was updated.	4-21								
	The A3P400 "208-Pin PQFP" pin table was updated.	4-25								
	The A3P060 "144-Pin FBGA" pin table was updated.	4-32								
	The A3P125 "144-Pin FBGA" pin table is new.	4-34								
	The A3P400 "144-Pin FBGA" is new.	4-38								
	The A3P400 "256-Pin FBGA" was updated.	4-48								
	The A3P1000 "256-Pin FBGA" was updated.	4-54								
	The A3P400 "484-Pin FBGA" was updated.	4-58								
	The A3P1000 "484-Pin FBGA" was updated.	4-68								
	The A3P250 "100-Pin VQFP*" pin table was updated.	4-14								
	The A3P250 "208-Pin PQFP*" pin table was updated.	4-23								
	The A3P1000 "208-Pin PQFP*" pin table was updated.	4-29								
	The A3P250 "144-Pin FBGA*" pin table was updated.	4-36								
	The A3P1000 "144-Pin FBGA*" pin table was updated.	4-32								
	The A3P250 "256-Pin FBGA*" pin table was updated.	4-45								
	The A3P1000 "256-Pin FBGA*" pin table was updated.	4-54								
The A3P1000 "484-Pin FBGA*" pin table was updated.	4-68									
Advance v0.5 (November 2005)	The "I/Os Per Package" table was updated for the following devices and packages:  <table data-bbox="443 1444 922 1560"> <tr> <td>Device</td> <td>Package</td> </tr> <tr> <td>A3P250/M7ACP250</td> <td>VQ100</td> </tr> <tr> <td>A3P250/M7ACP250</td> <td>FG144</td> </tr> <tr> <td>A3P1000</td> <td>FG256</td> </tr> </table>	Device	Package	A3P250/M7ACP250	VQ100	A3P250/M7ACP250	FG144	A3P1000	FG256	ii
Device	Package									
A3P250/M7ACP250	VQ100									
A3P250/M7ACP250	FG144									
A3P1000	FG256									
Advance v0.4	M7 device information is new.	N/A								
	The I/O counts in the "I/Os Per Package" table were updated.	ii								
Advance v0.3	The "I/Os Per Package" table was updated.	ii								
	M7 device information is new.	N/A								
	Table 2-4 • ProASIC3 Globals/Spines/Rows by Device was updated to include the number of rows in each top or bottom spine.	2-16								
	EXTFB was removed from Figure 2-24 • ProASIC3E CCC Options.	2-24								

Revision	Changes	Page
Advance v0.2, (continued)	Table 2-43 was updated.	2-64
	Table 2-18 was updated.	2-45
	Pin descriptions in the "JTAG Pins" section were updated.	2-51
	The "User I/O Naming Convention" section was updated.	2-48
	Table 3-7 was updated.	3-6
	The "Methodology" section was updated.	3-10
	Table 3-40 and Table 3-39 were updated.	3-33,3-32
	The A3P250 "100-Pin VQFP*" pin table was updated.	4-14
	The A3P250 "208-Pin PQFP*" pin table was updated.	4-23
	The A3P1000 "208-Pin PQFP*" pin table was updated.	4-29
	The A3P250 "144-Pin FBGA*" pin table was updated.	4-36
	The A3P1000 "144-Pin FBGA*" pin table was updated.	4-32
	The A3P250 "256-Pin FBGA*" pin table was updated.	4-45
	The A3P1000 "256-Pin FBGA*" pin table was updated.	4-54
The A3P1000 "484-Pin FBGA*" pin table was updated.	4-68	